

参考資料

October 2011

FXMA2102 Dual Supply, 2-Bit Voltage Translator / Buffer / Repeater / Isolator for I²C Applications

Features

- Bi-Directional Interface between Any Two Levels: 1.65V to 5.5V
- Direction Control not Needed
- System GPIO Resources Not Required when OE Tied to V_{CCA}
- I²C 400pF Buffer / Repeater
- I²C Bus Isolation
- A/B Port V_{OL} = 175mV (Typical), V_{IL} = 150mV,
 I_{OL} = 6mA
- Open-Drain Inputs / Outputs
- Accommodates Standard-Mode and Fast-Mode I²C-Bus Devices
- Supports I²C Clock Stretching & Multi-Master
- Fully Configurable: Inputs and Outputs Track V_{CC}
- Non-Preferential Power-Up; Either V_{CC} May Be Powered-Up First
- Outputs Switch to 3-State if Either V_{CC} is at GND
- Tolerant Output Enable: 5V
- Packaged in 8-Terminal Leadless MicroPak™ (1.6mm x 1.6mm) and Ultrathin MLP (1.2mm x 1.4m)
- ESD Protection Exceeds:
 - 8kV HBM ESD (per JESD22-A114)
 - 2kV CDM (per JESD22-C101)

Description

The FXMA2102 is a high-performance configurable dual-voltage-supply translator for bi-directional voltage translation over a wide range of input and output voltages levels.

Intended for use as a voltage translator between I²C-Bus[®] complaint masters and slaves.

The device is designed so that the A port tracks the V_{CCA} level and the B port tracks the V_{CCB} level. This allows for bi-directional A/B port voltage translation between any two levels from 1.65V to 5.5V. V_{CCA} can equal V_{CCB} from 1.65V to 5.5V.

Either V_{CC} can be powered-up first. Internal power-down control circuits place the device in 3-state if either V_{CC} is removed.

The two ports of the device have automatic direction sense capability. Either port may sense an input signal and transfer it as an output signal to the other port.

Ordering Information

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FXMA2102L8X	-40 to +85°C	XN	8-Lead MicroPak™, 1.6mm Wide	5000 Units on
FXMA2102UMX	-40 to +65 C		8-Lead Ultrathin MLP, 1.2mm x 1.4mm	Tape and Reel

Block Diagram

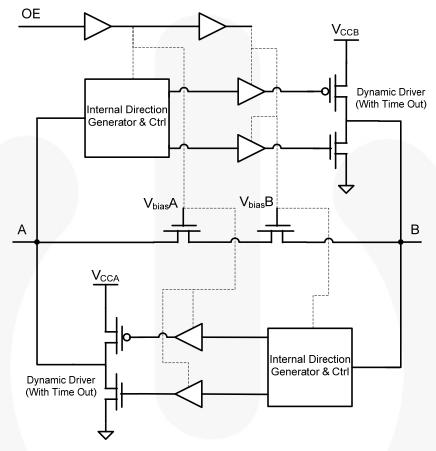


Figure 1. Block Diagram, 1 of 2 Channels

Pin Configuration

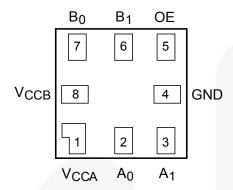


Figure 2. MicroPak™ (Top-Through View)

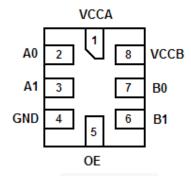


Figure 3. UMLP (Top-Through View)

Pin Definitions

Pin#	Name	Description
1	V _{CCA}	A-Side Power Supply
2, 3	A ₀ , A ₁	A-Side Inputs or 3-State Outputs
4	GND	Ground
5	OE	Output Enable Input
6, 7	B ₁ , B ₀	B-Side Inputs or 3-State Outputs
8	V _{CCB}	B-Side Power Supply

Truth Table

Control	Outpute		
OE	Outputs		
LOW Logic Level	3-State		
HIGH Logic Level	Normal Operation		

Note:

1. If the OE pin is driven LOW, the FXMA2102 is disabled and the A₀, A₁, B₀, and B₁ pins (including dynamic drivers) are forced into 3-state.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter	Min.	Max.	Unit	
V _{CCA} , V _{CCB}	Supply Voltage		-0.5	7.0		
		A Port	-0.5	7.0	V	
V_{IN}	DC Input Voltage	B Port	-0.5	7.0	V	
		Control Input (OE)	-0.5	7.0		
		A _n Outputs 3-State	-0.5	7.0		
\/	Output Voltage ⁽²⁾	B _n Outputs 3-State	-0.5	7.0	V	
Vo	Output Voltage	A _n Outputs Active	-0.5	V _{CCA} + 0.5V	V	
		B _n Outputs Active	-0.5	V _{CCB} + 0.5V		
I _{IK}	DC Input Diode Current	At V _{IN} < 0V		-50	mA	
	DC Output Diada Current	At V _O < 0V		-50	m 1	
I _{OK}	DC Output Diode Current	At V _O > V _{CC}		+50	mA	
I _{OH} / I _{OL}	DC Output Source/Sink Curr	rent	-50	+50	mA	
I _{cc}	DC V _{CC} or Ground Current p	er Supply Pin		±100	mA	
P_D	Power Dissipation	At 400KHz	\ \	0.129	mW	
T _{STG}	Storage Temperature Range	;	-65	+150	°C	
ESD	Electrostatic Discharge	Human Body Model, JESD22-A114		8	k)/	
ESD	Capability	Charged Device Mode, JESD22-C101		2	kV	

Note:

2. In absolute maximum rating must be observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol		Parameter	Min.	Max.	Unit
V _{CCA} , V _{CCB}	Power Supply Operating		1.65	5.50	V
V _{IN} Input Voltage		A Port	0	5.5	V
	Input Voltage	B Port	0	5.5	
		Control Input (OE)	0	V _{CCA}	
Θ _{JA} Thermal Resistance	8-Lead MicroPak™		279.0	CONN	
	8-Lead Ultrathin MLP			301.5	C°/W
T _A	Free Air Operating Temperature		-40	+85	°C

Note:

3. All unused inputs and I/O pins must be held at V_{CCI} or GND.

Functional Description

Power-Up/Power-Down Sequencing

FXM translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0V, outputs are in a high-impedance state. The control input (OE) is designed to track the V_{CCA} supply. A pull-down resistor tying OE to GND should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-down resistor is based upon the current-sinking capability of the device driving the OE pin.

The recommended power-up sequence is:

- 1. Apply power to the first V_{CC} .
- 2. Apply power to the second V_{CC} .
- 3. Drive the OE input HIGH to enable the device.

The recommended power-down sequence is:

- 1. Drive OE input LOW to disable the device.
- 2. Remove power from either V_{CC}.
- 3. Remove power from other $V_{\rm CC}$.

Note:

 Alternatively, the OE pin can be hardwired to V_{CCA} to save GPIO pins. If OE is hardwired to V_{CCA}, either V_{CC} can be powered up or down first.

Application Circuit

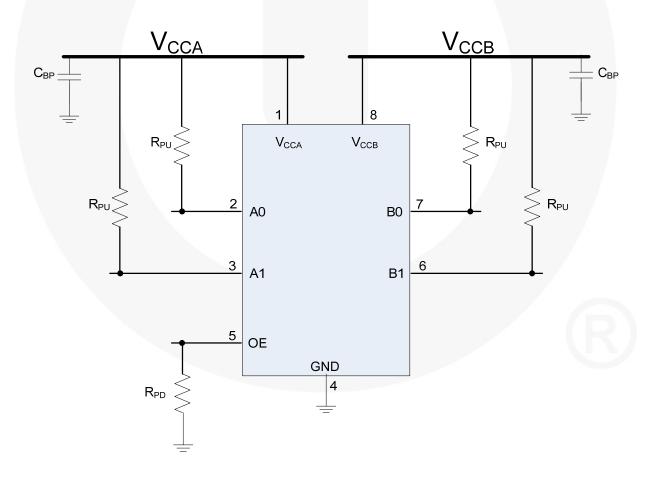


Figure 4. Application Circuit

Application Notes

The FXMA2102 has open-drain I/Os and requires external pull-up resistors on the four data I/O pins, as shown in Figure 4. If a pair of data I/O pins (A_n/B_n) is not used, both pins should be tied to GND (or both to V_{CC}). In this case, pull-down or pull-up resistors are not required. The recommended values for the pull-up resistors (RPU) are $1K\Omega$ to $10K\Omega$; however, depending on the total bus capacitance, the user is free to vary the pull-up resistor value to meet the maximum I²C edge rate per the I²C specification (UM10204 rev. 03, June 19, 2007). For example, the maximum edge rate (30% -70%) during fast mode (400kbit/s) is 300ns. If bus capacitance is approaching the maximum 400pF, lower the RPU value to keep the rise time below 300ns (Fast Mode). Section 7.1 of the I²C specification provides an excellent guideline for pull-up resistor sizing.

Theory of Operation

The FXMA2102 is designed for high-performance level shifting and buffer / repeating in an I^2C application. Figure 1 shows that each bi-directional channel contains two series-Npassgates and two dynamic drivers. This hybrid architecture is highly beneficial in an I^2C application where auto-direction is a necessity.

For example, during the following three I²C protocol events:

- Clock Stretching
- Slave's ACK Bit (9th bit = 0) following a Master's Write Bit (8th bit = 0)
- Clock Synchronization and Multi Master Arbitration

the bus direction needs to change from master to slave to slave to master without the occurrence of an edge. If there is an I^2C translator between the master and slave in these examples, the I^2C translator must change direction when both A and B ports are LOW. The Npassgates can accomplish this task very efficiently because, when both A and B ports are LOW, the Npassgates act as a low resistive short between the two (A and B) ports.

Due to I^2C 's open-drain topology, I^2C masters and slaves are not push/pull drivers. Logic LOWs are "pulled down" (I_{sink}), while logic HIGHs are "let go" (3-state). For example, when the master lets go of SCL (SCL always comes from the master), the rise time of SCL is largely determined by the RC time constant, where R = R_{PU} and C = the bus capacitance. If the FXMA2102 is attached to the master [on the A port] in this example, and there

is a slave on the B port, the Npassgates act as a low resistive short between both ports until either of the port's $V_{\rm CC}/2$ thresholds are reached. After the RC time constant has reached the $V_{\rm CC}/2$ threshold of either port, the port's edge detector triggers both dynamic drivers to drive their respective ports in the LOW-to-HIGH (LH) direction, accelerating the rising edge. The resulting rise time resembles the scope shot in Figure 5. Effectively, two distinct slew rates appear in rise time. The first slew rate (slower) is the RC time constant of the bus. The second slew rate (much faster) is the dynamic driver accelerating the edge.

If both the A and B ports of the translator are HIGH, a high-impedance path exists between the A and B ports because both the Npassgates are turned off. If a master or slave device decides to pull SCL or SDA LOW, that device's driver pulls down ($l_{\rm sink}$) SCL or SDA until the edge reaches the A or B port $V_{\rm CC}/2$ threshold. When either the A or B port threshold is reached, the port's edge detector triggers both dynamic drivers to drive their respective ports in the HIGH-to-LOW (HL) direction, accelerating the falling edge.

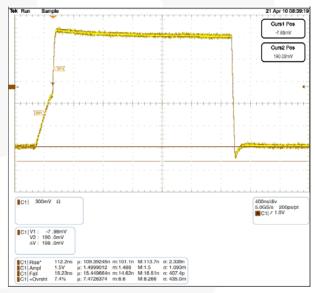


Figure 5. FXMA2102 Waveform C: 600pF, Rpu: 2.2K

Buffer / Repeater Performance

The FXMA2102 dynamic drivers have enough current sourcing capability to drive a 400pF capacitive bus. This is beneficial for instances when an $\rm I^2C$ buffer / repeater is required. The $\rm I^2C$ specification stipulates a maximum bus capacitance of 400pF. If an $\rm I^2C$ segment exceeds 400pF, an $\rm I^2C$ buffer / repeater is required to split the segment into two segments, each of which is less than 400pF. Figure 5 is a scope shot of an FXMA2102 driving a lumped load of 600pF. Notice the (30% - 70%) rise time is only 112ns ($\rm R_{PU}$ = 2.2K). This is well below the maximum edge rate of 300ns. Not only does the FXMA2102 drive 400pF, but it also provides excellent headroom below the $\rm I^2C$ specification maximum edge rate of 300ns.

Vol vs. IoL

The l^2C specification mandates a maximum V_{lL} (l_{OL} of 3mA) of V_{CC} • 0.3 and a maximum V_{OL} of 0.4V. If there is a master on the A port of an l^2C translator with a V_{CC} of 1.65V and a slave on the l^2C translator B port with a V_{CC} of 3.3V, the maximum V_{lL} of the master is (1.65V x 0.3) 495mV. The slave could legally transmit a valid logic LOW of 0.4V to the master.

If the I^2C translator's channel resistance is too high, the voltage drop across the translator could present a V_{IL} to the master greater than 495mV. To complicate matters, the I^2C specification states that 6mA of I_{OL} is recommended for bus capacitances approaching 400pF. More I_{OL} increases the voltage drop across the I^2C translator. The I^2C application benefits when I^2C translators exhibit low V_{OL} performance. Figure 6 depicts typical FXMA2102 V_{OL} performance vs. the competition, given a 0.4V V_{IL} .

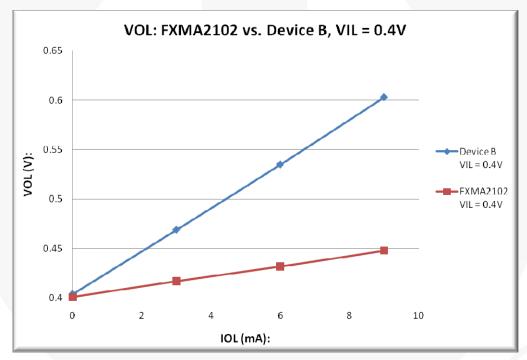


Figure 6. Vol vs. IoL

I²C-Bus[®] Isolation

The FXMA2102 supports I²C-Bus isolation for the following conditions:

- Bus isolation if bus clear
- Bus isolation if either V_{CC} goes to ground

Bus Clear

Because the I²C specification defines the minimum SCL frequency of DC, the SCL signal can be held LOW forever; however, this condition shuts down the I²C bus. The I²C specification refers to this condition as "Bus Clear". In Figure 7, if slave #2 holds down SCL forever, the master and slave #1 are not able to communicate, because the FXMA2102 passes the SCL stuck-LOW condition from slave #2 to slave #1 as well as the

master. However, if the OE pin is pulled LOW (disabled), both ports (A and B) are 3-stated. This results in the FXMA2102 isolating slave #2 from the master and slave #1, allowing full communication between the master and slave #1.

Either V_{CC} to GND

If slave #2 is a camera that is suddenly removed from the I^2C bus, resulting in V_{CCB} transitioning from a valid V_{CC} (1.65V – 5.5V) to 0V, the FXMA2102 automatically forces SCL and SDA on both its A and B ports into 3-state. Once V_{CCB} has reached 0V, full I^2C communication between the master and slave #1 remains undisturbed.

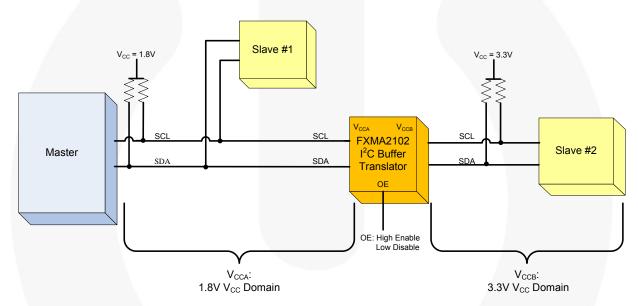


Figure 7. Bus Isolation

DC Electrical Characteristics

 $T_A = -40^{\circ}C \text{ to } +85^{\circ}C.$

Symbol	Parameter		Condition	V _{CCA} (V)	V _{CCB} (V)	Min.	Max.	Unit
V	High Level Input	Data	Data Inputs A _n		1.65-5.50	V _{CCA} - 0.4		V
V_{IHA}	Voltage A	Contr	ol Input OE	1.65–5.50	1.65-5.50	0.7 x V _{CCA}		v
V_{IHB}	High Level Input Voltage B	Data	Inputs B _n	1.65–5.50	1.65–5.50	V _{CCB} - 0.4		٧
\/	Low Level Input	Data	Inputs A _n	1.65-5.50	1.65-5.50		0.4	V
V_{ILA}	Voltage A	Contr	ol Input OE	1.65–5.50	1.65-5.50		0.3 x V _{CCA}	V
V_{ILB}	Low Level Input Voltage B	Data	Inputs B _n	1.65–5.50	1.65–5.50		0.4	V
V	Low Level Output	V _{IL} =	0.15V	165 5 50	165 5 50		0.4	V
V_{OL}	Voltage	I _{OL} = 6mA		1.65–5.50	1.65–5.50		0.4	V
IL	Input Leakage Current		ol Input OE, V _{CCA} or GND	1.65–5.50	1.65–5.50		±1.0	μA
/	Power Off	A_n	V_{IN} or $V_O = 0V$ to 5.5V	0	5.50		±2.0	
I _{OFF}	Leakage Current	B _n	V_{IN} or V_{O} = 0V to 5.5V	5.50	0		±2.0	μA
		A _n , B _n	$V_O = 0V$ to 5.5V, OE = V_{IL}	5.50	5.50		±2.0	
l _{OZ}	3-State Output Leakage ⁽⁶⁾	A _n	$V_O = 0V$ to 5.5V, OE = Don't Care	5.50	0		±2.0	μA
		B _n	$V_O = 0V$ to 5.5V, OE = Don't Care	0	5.50		±2.0	
I _{CCA} / _B	Quiescent Supply Current ^(7,8)	$V_{IN} = V_{CCI}$ or GND, $I_O = 0$		1.65–5.50	1.65–5.50		5.0	μA
I _{CCZ}	Quiescent Supply Current ⁽⁷⁾	$V_{IN} = V_{CCI}$ or GND, $I_O = 0$, OE = V_{IL}		1.65-5.50	1.65–5.50		5.0	μA
	Quiescent Supply	escent Supply $V_{IN} = 5.5V$ or GND, $I_O = 0$,		0	1.65-5.50		-2.0	
I _{CCA}	Current ⁽⁶⁾		OE = Don't Care, B_n to A_n		0		2.0	μA
1	Quiescent Supply	V _{IN} =	5.5V or GND, I _O = 0,	1.65-5.50	0		-2.0	μA
I _{CCB}	Current ⁽⁶⁾	OE =	Don't Care, A _n to B _n	0	1.65-5.50		2.0	μA

Notes:

- 5. This table contains the output voltage for static conditions. Dynamic drive specifications are given in Dynamic Output Electrical Characteristics.
- 6. "Don't Care" indicates any valid logic level.
- 7. V_{CCI} is the V_{CC} associated with the input side.
- 8. Reflects current per supply, V_{CCA} or V_{CCB} .

Dynamic Output Electrical Characteristics

Output Rise / Fall Time

Output load: C_L = 50pF, R_{PU} = 2.2k Ω , push / pull driver, and T_A = -40°C to +85°C.

		V _{cco} ⁽¹⁰⁾					
Symbol	Parameter	4.5 to 5.5V	3.0 to 3.6V	2.3 to 2.7V	1.65 to 1.95V	Unit	
		Тур.	Тур.	Тур.	Тур.		
t _{rise}	Output Rise Time; A Port, B Port ⁽¹¹⁾	3	4	5	7	ns	
t _{fall}	Output Fall Time; A Port, B Port ⁽¹²⁾	1	1	1	1	ns	

Notes:

- 9. Output rise and fall times guaranteed by design simulation and characterization; not production tested.
- 10. V_{CCO} is the V_{CC} associated with the output side.
- 11. See Figure 12.
- 12. See Figure 13.

Maximum Data Rate(13)

Output load: C_L = 50pF, R_{PU} = 2.2k Ω , push / pull driver, and T_A = -40°C to +85°C.

		V _{CCB}					
V _{CCA}	Direction	4.5 to 5.5V	3.0 to 3.6V	2.3 to 2.7V	1.65 to 1.95V	Unit	
		Min.	Min.	Min.	Min.		
4 5\/ to 5 5\/	A to B	50	50	40	30	N/I I=	
4.5V to 5.5V	B to A	50	50	40	40	MHz	
2.0)/45.2.6)/	A to B	50	50	40	19	N/11-	
3.0V to 3.6V	B to A	50	50	40	40	MHz	
2 2)/+= 2 7)/	A to B	40	40	30	19	N/I I-	
2.3V to 2.7V	B to A	40	40	30	30	MHz	
1.65\/ to 1.05\/	A to B	40	40	30	19	MHz	
1.65V to 1.95V	B to A	30	30	19	19	IVITIZ	

Note:

13. F-toggle guaranteed by design simulation; not production tested.

AC Characteristics

Output Load: C_L = 50pF, R_{PU} = 2.2k Ω , and T_A = -40°C to +85°C.

			V _{CCB}							
Symbol	Parameter	4.5 to	4.5 to 5.5V 3.0 to 3.6V			2.3 to 2.7V		1.65 to 1.95V		Unit
		Тур.	Max.	Тур.	Max.	Тур.	Max.	Тур.	Max.	
V _{CCA} = 4.5	5 to 5.5V				•	•				
	A to B	1	3	1	3	1	3	1	3	
t_{PLH}	B to A	1	3	2	4	3	5	4	7	ns
	A to B	2	4	3	5	4	6	5	7	
t _{PHL}	B to A	2	4	2	5	2	6	5	7	ns
	OE to A	4	5	6	10	5	9	7	15	
t_{PZL}	OE to B	3	5	4	7	5	8	10	15	ns
	OE to A	65	100	65	105	65	105	65	105	
t_{PLZ}	OE to B	5	9	6	10	7	12	9	16	ns
t _{skew}	A Port, B Port ⁽¹⁴⁾	0.50	1.50	0.50	1.00	0.50	1.00	0.50	1.00	ns
V _{CCA} = 3.0) to 3.6V					1				
	A to B	2.0	5.0	1.5	3.0	1.5	3.0	1.5	3.0	
t _{PLH}	B to A	1.5	3.0	1.5	4.0	2.0	6.0	3.0	9.0	ns
7	A to B	2.0	4.0	2.0	4.0	2.0	5.0	3.0	5.0	
t _{PHL}	B to A	2.0	4.0	2.0	4.0	2.0	5.0	3.0	5.0	ns
	OE to A	4.0	8.0	5.0	9.0	6.0	11.0	7.0	15.0	ns
t _{PZL}	OE to B	4.0	8.0	6.0	9.0	8.0	11.0	10.0	14.0	
	OE to A	100	115	100	115	100	115	100	115	ns
t_{PLZ}	OE to B	5	10	4	8	5	10	9	15	
t _{skew}	A Port, B Port ⁽¹⁴⁾	0.5	1.5	0.5	1.0	0.5	1.0	0.5	1.0	ns
V _{CCA} = 2.3			I.	ı	ı		ı		I	
	A to B	2.5	5.0	2.5	5.0	2.0	4.0	1.0	3.0	
t _{PLH}	B to A	1.5	3.0	2.0	4.0	3.0	6.0	5.0	10.0	ns
	A to B	2.0	5.0	2.0	5.0	2.0	5.0	3.0	6.0	
t _{PHL}	B to A	2.0	5.0	2.0	5.0	2.0	5.0	3.0	6.0	ns
	OE to A	5.0	10.0	5.0	10.0	6.0	12.0	9.0	18.0	
t_{PZL}	OE to B	4.0	8.0	4.5	9.0	5.0	10.0	9.0	18.0	ns
	OE to A	100	115	100	115	100	115	100	115	
t_{PLZ}	OE to B	65	110	65	110	65	115	12	25	ns
t _{skew}	A Port, B Port ⁽¹⁴⁾	0.5	1.5	0.5	1.0	0.5	1.0	0.5	1.0	ns
	65 to 1.95V		l				l			
	A to B	4	7	4	7	5	8	5	10	
t_{PLH}	B to A	1.0	2.0	1.0	2.0	1.5	3.0	5.0	10.0	ns
	A to B	5	8	3	7	3	7	3	7	
t_{PHL}	B to A	4	8	3	7	3	7	3	7	ns
	OE to A	11	15	11	14	14	28	14	23	
t_{PZL}	OE to B	6	14	6	12	6	12	9	16	ns
	OE to A	75	115	75	115	75	115	75	115	
t_{PLZ}	OE to B	75	115	75	115	75	115	75	115	ns
t _{skew}	A Port, B Port ⁽¹⁴⁾	0.5	1.5	0.5	1.0	0.5	1.0	0.5	1.0	ns

Note:

^{14.} Skew is the variation of propagation delay between output signals and applies only to output signals on the same port (A_n or B_n) and switching with the same polarity (LOW-to-HIGH or HIGH-to-LOW) (see Figure 15). Skew is guaranteed, but not tested.

Capacitance

 $T_A = +25$ °C.

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance Control Pin (OE)	$V_{CCA} = V_{CCB} = GND$	2.2	pF
C _{I/O}	Input/Output Capacitance, A _n , B _n	$V_{CCA} = V_{CCB} = 5.0V$, OE = GND, VA = VB = 5.0V	13.0	pF
$C_{\sf pd}$	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 5.0V$, $V_{IN} = 0V$ or V_{CC} , $f = 400KHz$	13.5	pF

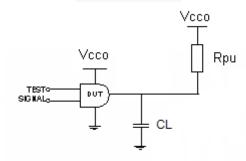


Figure 8. AC Test Circuit

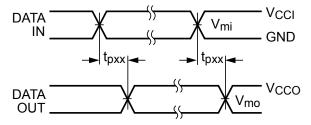
Table 1. Propagation Delay Table

Test	Input Signal	Output Enable Control
t _{PLH} , t _{PHL}	Data Pulses	V _{CCA}
t_{PZL} (OE to A_n , B_n)	0V	LOW to HIGH Switch
t_{PLZ} (OE to A_n , B_n)	0V	HIGH to LOW Switch

Table 2. AC Load Table

V _{cco}	C _L	R_L
1.8 ± 0.15V	50pF	2.2kΩ
2.5 ± 0.2V	50pF	2.2kΩ
3.3 ± 0.3V	50pF	2.2kΩ
5.0 ± 0.5V	50pF	2.2kΩ

Timing Diagrams



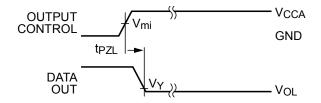
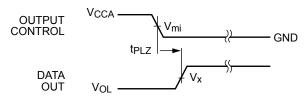


Figure 9. Waveform for Inverting and Non-Inverting Functions⁽¹⁵⁾

Figure 10. 3-STATE Output Low Enable Time⁽¹⁵⁾



Symbol	V _{cc}
V _{mi} ⁽¹⁶⁾	V _{CCI} / 2
V_{mo}	V _{CCO} / 2
V _X	0.5 x V _{CCO}
V_{Y}	0.1 x V _{CCO}

Figure 11. 3-STATE Output High Enable Time⁽¹⁵⁾

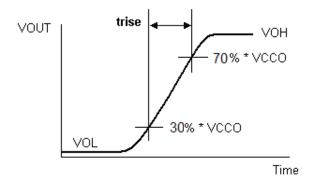


Figure 12. Active Output Rise Time

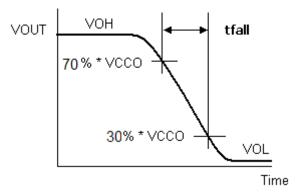
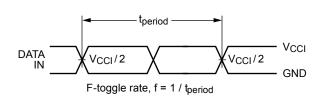
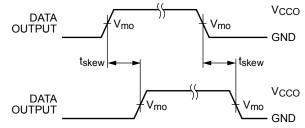


Figure 13. Active Output Fall Time





 $t_{skew} = (t_{pHLmax} - t_{pHLmin}) \text{ or } (t_{pLHmax} - t_{pLHmin})$

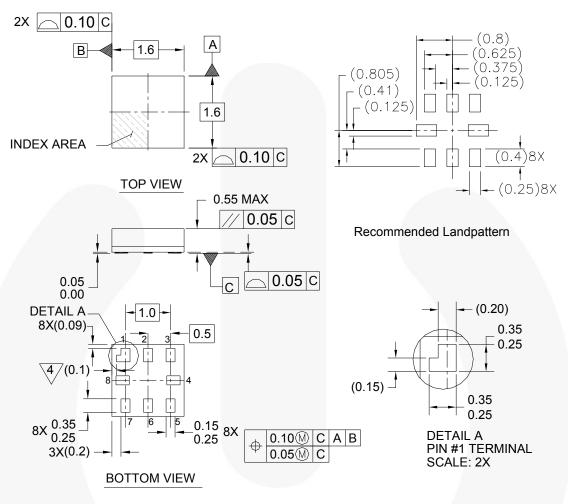
Figure 14. F-Toggle Rate

Figure 15. Output Skew Time

Notes:

- 15. Input $t_R = t_F = 2.0$ ns, 10% to 90% at $V_{IN} = 1.65$ V to 1.95V; Input $t_R = t_F = 2.0$ ns, 10% to 90% at $V_{IN} = 2.3$ to 2.7V; Input $t_R = t_F = 2.5$ ns, 10% to 90%, at $V_{IN} = 3.0$ V to 3.6V only; Input $t_R = t_F = 2.5$ ns, 10% to 90%, at $V_{IN} = 4.5$ V to 5.5 only.
- 16. $V_{CCI} = V_{CCA}$ for control pin OE or $V_{mi} = (V_{CCA} / 2)$.

Physical Dimensions



Notes:

- 1. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y.14M-1994
- 4/PIN 1 FLAG, END OF PACKAGE OFFSET
- 5. DRAWING FILE NAME: MKT-MAC08AREV4

MAC08AREV4

Figure 16. 8-Lead MicroPak™, 1.6mm Wide

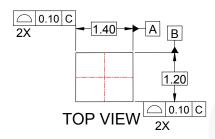
Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

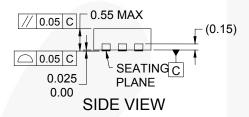
Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/.

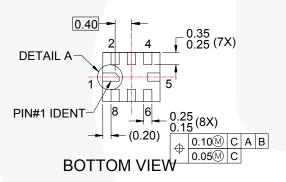
Tape & Reel Format for MicroPak™

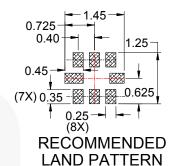
Always visit Fairchild Semiconductor's online packaging area for the most recent tape and reel specifications: http://www.fairchildsemi.com/products/logic/pdf/micropak_tr.pdf.

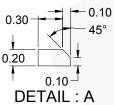
Physical Dimensions











SCALE: 2X

NOTES:

- A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC STANDARD.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. LAND PATTERN RECOMMENDATION IS BASED ON FSC DESIGN ONLY.
- E. DRAWING FILENAME: MKT-UMLP08Arev2.

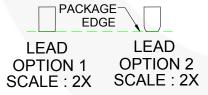


Figure 17. 8-Lead Ultrathin MLP, 1.2mm x 1.4mm

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/.

Tape & Reel Format for MicroPak™

Always visit Fairchild Semiconductor's online packaging area for the most recent tape and reel specifications: http://www.fairchildsemi.com/dwg/UM/UMLP08A.pdf.





The Power Franchise®

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

TinyBoost™ Green FPS™ Programmable Active Droop™ BitSiC™ TinyBuck™ Build it Now™ Green FPS™ e-Series™ OFET TinyCalc™ QS™ Gmax™ CorePLUS™ TinyLogic[®] GTO™ Quiet Series™ CorePOWER™ TINYOPTO™ RapidConfigure™ IntelliMAX™ CROSSVOLT™ TinyPower™ ISOPLANAR™ CTL™ TinyPWM™

Making Small Speakers Sound Louder Current Transfer Logic™ TinyWire™ Saving our world, 1mW/W/kW at a time™ and Better™ DEUXPEED[®] SignalWise™ TranSiC™ MegaBuck™ Dual Cool™ SmartMax™ TriFault Detect™ MICROCOUPLER™ EcoSPARK[®] SMART START™ TRUECURRENT®*

EfficientMax™ MicroFET™ Similar 1 TRUECURRE
ESBC™ MicroPak™ Solutions for Your Success™ μSerDes™

ESBC™ Solutions for Your Success™ μSerDes™

MicroPak2TM

MillerDriveTM

SPM®

STEALTHTM

MillerDriveTM

SuperFET®

SuperFET® **UHC®** Fairchild® MotionMax™ SuperSOT™-3 Fairchild Semiconductor® Ultra FRFET™ Motion-SPM™ SuperSOT™-6 UniFET™ FACT Quiet Series™ mWSaver™ FACT® SuperSOT™-8 VCX™ OptoHiT™ SupreMOS® VisualMax™ OPTOLOGIC® FastvCore™ SyncFET™ VoltagePlus™ OPTOPLANAR® Sync-Lock™ FETBench™ XS™

FlashWriter®*

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a)
 are intended for surgical implant into the body or (b) support or
 sustain life, and (c) whose failure to perform when properly used in
 accordance with instructions for use provided in the labeling, can be
 reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Definition of Terms		
Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I58

^{*} Trademarks of System General Corporation, used under license by Fairchild Semiconductor.